

# 9 bit Level Shifter/Transceiver With 3 State Outputs

REJ03D0300-0500 Rev.5.00 May 10, 2006

### Description

The HD151015 is an IC which consists of 9 bus transceivers (three state output) in a 24 pin package. Signals are transmitter from A to B when the direction control input (DiR) is at a high level, and from B to A when DiR is at a low level. When the enable input ( $\overline{G}$ ) is high, A and B are isolated. And this product has two terminals (V<sub>CCA</sub>, V<sub>CCB</sub>), V<sub>CCA</sub> is connected with control input and A bus side, V<sub>CCB</sub> is connected with B bus side. V<sub>CCA</sub> and V<sub>CCB</sub> are isolated. Consequently, it is best to change the level in case of two supply voltage coexist on one board and application of power management.

### Features

- This product function as level shift transceiver that change  $V_{CCA}$  input level to  $V_{CCB}$  output level,  $V_{CCB}$  input level to  $V_{CCA}$  output level by providing different supply voltages to  $V_{CCA}$  and  $V_{CCB}$ .
- This product is able to the power management : Turn on and off the supply on V<sub>CCB</sub> side with providing the supply of V<sub>CCA</sub>.

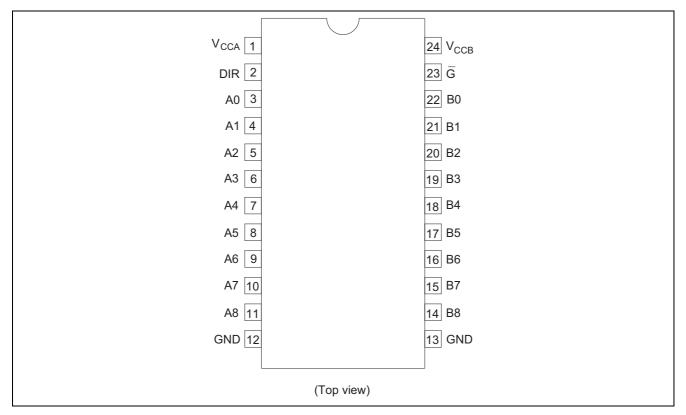
(Enable input  $(\overline{G})$  : High level)

- Inputs and outputs are CMOS level, and the power dissipation is the same as CMOS standard logic.
- Wide operating supply voltage range:
- $V_{CCA} = V_{CCB} = 2 \text{ to } 6 \text{ V} (V_{CCB} \ge V_{CCA} 0.5 \text{ V})$
- Wide operating temperature range: Ta = -40 to  $85^{\circ}C$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)	
HD151015TEL		PTSP0024JB-A (TTP-24DBV)	T	EL (1,000 pcs/reel)	



# **Pin Arrangement**



# **Function Table**

Inputs		
G	DIR	Outputs
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Z

H : High level

L : Low level

Z : High Impedance

X : Immaterial

# **Absolute Maximum Ratings**

ltem	Symbol	Rating	Unit	Conditions
Supply Voltage	$V_{CCA}, V_{CCB}$	–0.5 to +7.0	V	
Input Diode Current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> = -0.5
		20	mA	$V_{I} = V_{CC} + 0.5$
Input Voltage	V <sub>IN</sub>	–0.5 to V <sub>CC</sub> + 0.5	V	
Output Diode Current	I <sub>ок</sub>	-50	mA	V <sub>O</sub> = -0.5
		50	mA	$V_{\rm O} = V_{\rm CC} + 0.5$
Output Voltage	V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> + 0.5	V	
Output Current	lo	±50	mA	
VCC or Ground Current	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	per output pin
Storage Temperature	Tstg	–65 to + 150	°C	

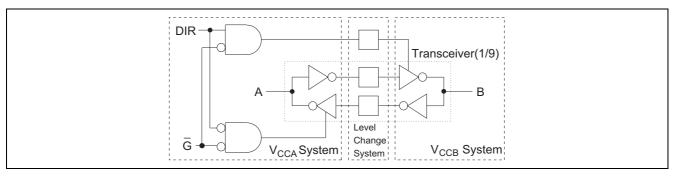
Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

# **Recommended Operating Conditions**

ltem	Symbol	Rating	Unit	Conditions
Supply voltage	V <sub>CCA, B</sub>	2.0 to 6.0	V	$V_{CCB} \ge V_{CCA} - 0.5 V$
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Output voltage	Vout	0 to V <sub>CC</sub>	V	
Operating Temperature	TA	-40 to +85	°C	
Input Rise and Fall Time* <sup>1</sup>	t <sub>r</sub> , t <sub>f</sub>	8	ns/V	V <sub>CC</sub> @3.0 V (Input DiR, G, A)
				V <sub>CC</sub> @4.5 V (Input B)
				V <sub>CC</sub> @5.5 V (Input B)

Note: 1. The item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

# Logick Diagram



# **Electrical Characteristics**

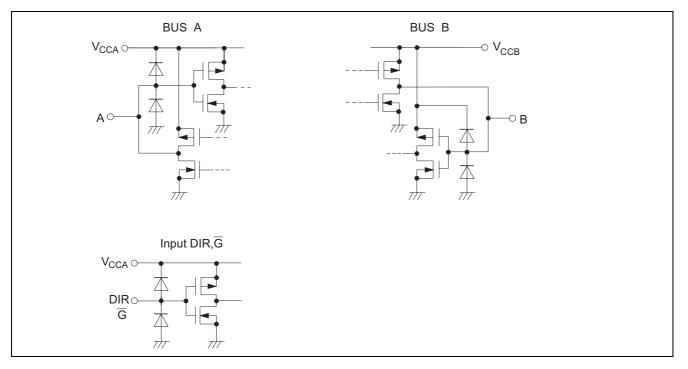
	Sym-	V <sub>CCA</sub>	V <sub>CCB</sub>	1	Га = 25	°C		–40 to °C				
Item	bol	(V)	(V)	Min	Тур	Max	Min	Max	Unit	Conditions		
Input Voltage	VIH	3.0	3.0	2.1	1.5	—	2.1	—	V	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$		
		4.5	4.5	3.15	2.25	—	3.15	—	1			
		5.5	5.5	3.85	2.75	—	3.85	—	1			
	VIL	3.0	3.0		1.5	0.9	—	0.9	V	V <sub>OUT</sub> = 0.1 V	or V <sub>CC</sub> – 0.1 V	
		4.5	4.5		2.25	1.35	—	1.35	1			
		5.5	5.5		2.75	1.65	—	1.65	1			
Output	V <sub>OH</sub>	2.7	4.5	2.6	2.69	—	2.6	—	V	V <sub>IN</sub> = V <sub>IL</sub> or V	<sub>IH</sub> , I <sub>OH</sub> = –50 µА	A* <sup>1</sup>
Voltage		2.7	4.5	4.4	4.49	—	4.4	—	1	V <sub>IN</sub> = V <sub>IL</sub> or V	<sub>ін</sub> , І <sub>он</sub> = –50 µА	В
		2.7	4.5	2.3		—	2.2	—	V	V <sub>IN</sub> =	I <sub>OH</sub> = -4 mA	A
		2.7	4.5	3.9		—	3.8	—	1	VIL or VIH	I <sub>OH</sub> = –12 mA	В
	Vol	2.7	4.5	—	0.001	0.1	_	0.1	V	V <sub>IN</sub> = V <sub>IL</sub> or V	<sub>IH</sub> , I <sub>OL</sub> = 50 μA	A.B
		2.7	4.5	—		0.32	_	0.37	V	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> , I <sub>OL</sub> = 12 mA A.B		A.B
Input Current	l <sub>in</sub>	3.3	5.5	—		±0.1	_	±1.0	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND		
Off State	l <sub>oz</sub>	3.3	5.5	—		±0.5	_	±5.0	μA	$V_{IN}(\overline{G}) = V_{IH}, V_{IN} = V_{CC} \text{ or } GND,$		
Output										V <sub>OUT</sub> = V <sub>CC</sub> or	GND	
Current												
Supply	I <sub>CCA.B</sub>	3.3	5.5	—	—	8.0	—	80	μA	$V_{IN} = V_{CC} \text{ or } GND$		
Current	ICCA	5.5	0	_	—	8.0	_	80	μA	$V_{IN} = V_{CC}$ or GND, B Input OPEN		

Note: 1. A: Output A, B: Output B, A.B: Output A.B

		Ta = 25°C			Ta = -40 to 85°C			
		$V_{CCA} = 3.0 V, V_{CCB} = 5.0 V$		$V_{CC} = 2.7 V, V_{CCB} = 4.5 V$				
Item	Symbol	Min Typ Max		Min	Max	Unit	Conditions	
Propagation Delay Time	t <sub>PLH</sub>	1.0	5.0	10.0	1.0	12.0	ns	$B \to A$
		1.0	5.0	10.0	1.0	12.0		$A \rightarrow B$
	t <sub>PHL</sub>	1.0	5.0	10.0	1.0	12.0	ns	$B \to A$
		1.0	5.0	10.0	1.0	12.0		$A \rightarrow B$
Output Enable Time	t <sub>zH</sub>	1.0	8.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	8.0	16.0	1.0	20.0		$\overline{G} \to B$
	t <sub>ZL</sub>	1.0	9.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	9.0	16.0	1.0	20.0		$\overline{G} \to A$
Output Disable Time	t <sub>HZ</sub>	1.0	9.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	9.0	16.0	1.0	20.0		$\overline{G} \to B$
	t <sub>LZ</sub>	1.0	8.0	16.0	1.0	20.0	ns	$\overline{G} \to A$
		1.0	8.0	16.0	1.0	20.0		$\overline{G} \to B$

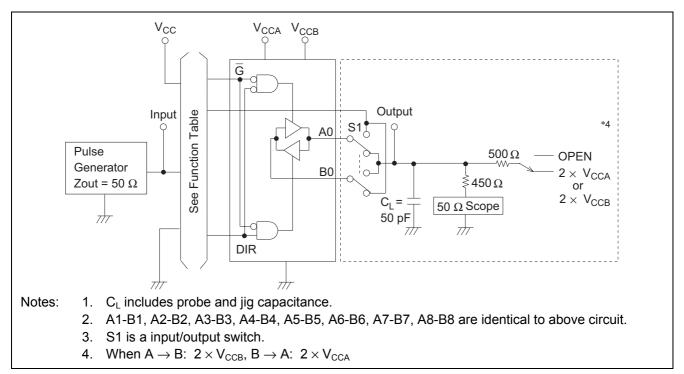
# **Switching Characteristics**

# Input and Output Equivalent Circuit

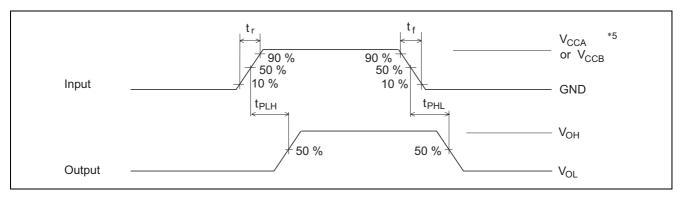


# **Switching Time Test Method**

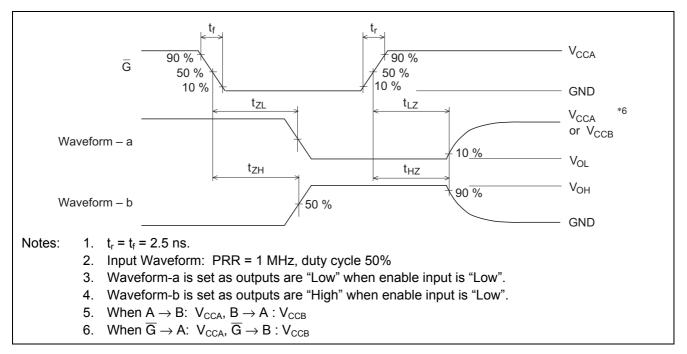
### **Test Circuit**



#### Waveforms-1

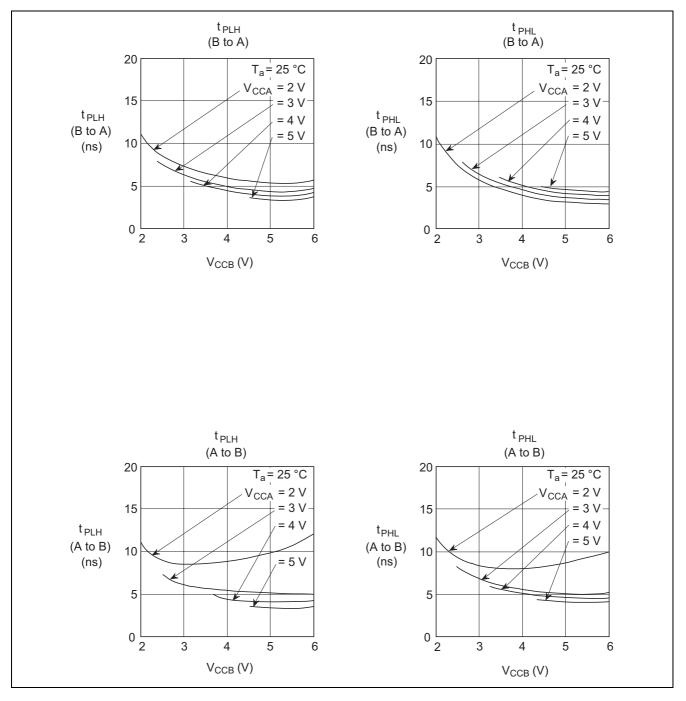


#### Waveforms-2

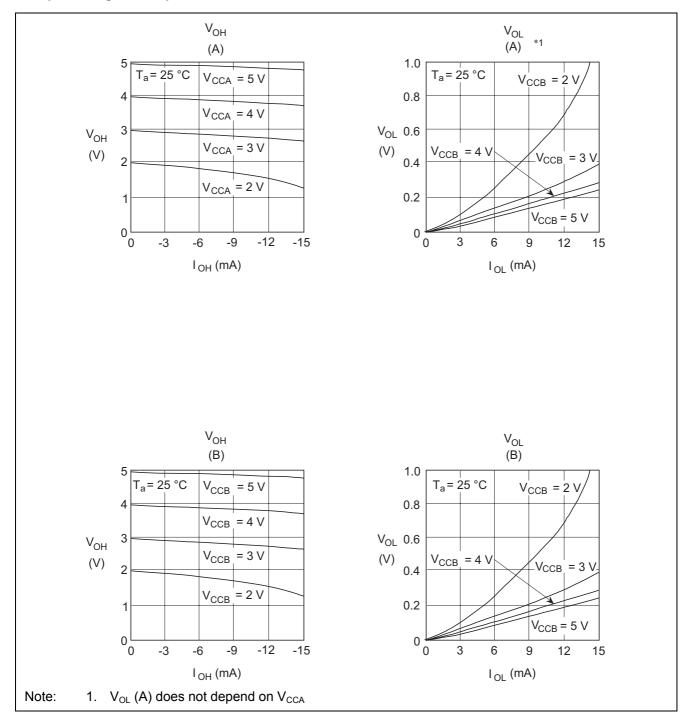


# **Typical Characteristic Curves**

### Propagation Delay Times vs Power Supply ( $V_{CCA}$ , $V_{CCB}$ )

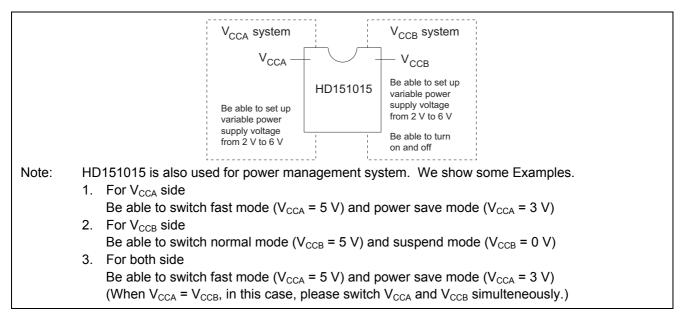


#### **Output Voltage vs Output Current**

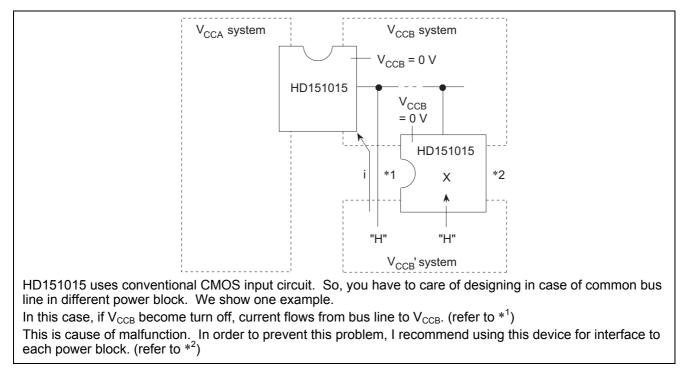


### Application

#### For power management system (1)



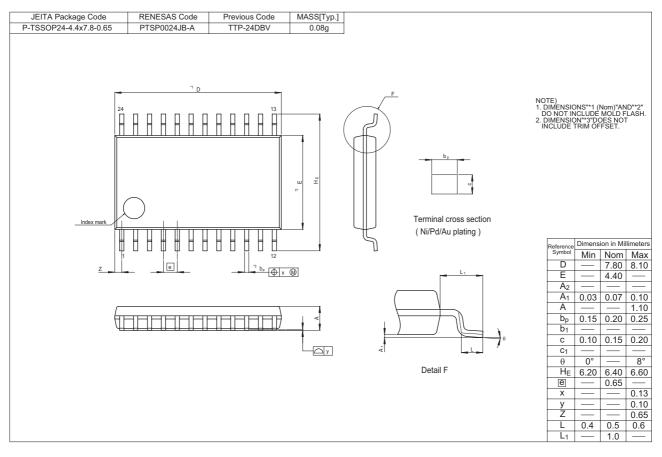
For power management system (2) (Common bus line in different power system)



#### [Cautions on using]

Please use this IC on condition of  $V_{CCA}$  usually ON, because if you use it on condition of  $V_{CCA}$  being OFF,  $V_{CCB}$  being ON, it will be troubled.

# **Package Dimensions**



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